## New Jersey Semi-Conductor Products, Inc.

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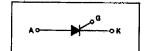
# Silicon Controlled Rectifiers Reverse Blocking Triode Thyristors

... fast switching, high-voltage Silicon Controlled Rectifiers especially designed for pulse modulator applications in radar and other similar equipment.

- High-Voltage: VDRM = 300 to 800 Volts
- Turn-On Times: in Nanosecond Range
- Repetitive Pulse Current to 100 Amps
- Stable Switching Characteristics Over an Operating Temperature Range From -65 to +105°C
- Pulse Repetition Rates as High as 10,000 pps

MCR729-5 thru MCR729-10

SCRs 5 AMPERES RMS 300 thru 800 VOLTS





(TO-64)

### MAXIMUM RATINGS (TJ = 105°C unless otherwise noted.)

Characteristic	Symbol	Value	Unit	
Peak Repetitive Forward Blocking Voltage, Note 1  MCR729-5  -6 -7 -8 -9 -10	VDRM	300 400 500 600 700 800	Volts	
Peak Repetitive Reverse Blocking Voltage, Note 1	VRRM	50	Volts	
Forward Current RMS	T(RMS)	5	Amps	
Average Forward Power	PF(AV)	5	Watts	
Peak Repetitive On-State Control (PW = 10 μs)	ITRM	100	Amps	
Peak Forward Gate Power	PGFM	20	Watts	
Average Forward Gate Power	PGF(AV)	1	Watt	
Peak Forward Gate Current	GFM	5	Amps	
Peak Forward Gate Voltage	VGFM	10	Volts	
Peak Reverse Gate Voltage	VGRM	10	Volts	
Operating Junction Temperature Range	Tj	-65 to +105	°C	
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C	
Stud Torque		15	in, lb,	

Note 1. Ratings apply for zero or negative gate voltages. Devices shall not have a positive bias to the gate concurrently with a negative potential on the anode. Devices should not be tested with a constant current source for forward and reverse blocking voltages such that the applied voltage exceeds the ratings.

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

#### MCR729-5 thru MCR729-10

#### ELECTRICAL CHARACTERISTICS (Tc = 25°C unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
Peak Forward or Reverse Blocking Current (Rated VDRM or VRRM, gate open) TC = 105°C	IDRM, IRRM	-	0.2	2	mA
Gate Trigger Current (Continuous dc) (V <sub>D</sub> = 7 Vdo, R <sub>L</sub> = 100 ohms)	GT	-	10	50	mAdc
Gate Trigger Voltage (Continuous dc) (VD = 7 Vdo, RL = 100 ohms)	V <sub>GT</sub>	_	0.8	1.5	Voits
Holding Current (V <sub>D</sub> = 7 Vdc, gate open)	lH	3	16	_	mA
Forward On Voltage (I <sub>TM</sub> = 5 A, PW ≤ 1 ms, Duty Cycle ≤ 1%)	VTM	-	-	2.6	Voits
Dynamic Forward On Voltage (0.5 \( \mu \) safter 50\% pt, I <sub>G</sub> = 200 mA, V <sub>D</sub> = Rated VDRM, \( \frac{1}{2}F(pulse) \( \nu \) 30 Amps)	ΥTM		15	25	Volts
Turn-On Time $(t_d + t_f)$ $(l_G = 200 \text{ mA, V}_D = \text{Rated V}_{DRM})$ $(l_{TM} = 30 \text{ Amps peak})$ $(l_{TM} = 100 \text{ Amps peak})$	<sup>t</sup> on		200 400		ns
Turn-On Time Variation (TC = +25°C to +105°C and -65°C to +25°C, I <sub>TM</sub> = 30 A)	ton	-	±600	_	กร
Pulse Turn-Off Time (If(pulse) = 30 Amps, I <sub>reverse</sub> = 0) (Inductive charging circuit)	t <sub>rec</sub>	_	15	_	μs
Forward Voltage Application Rate (Linear Rate of Rise) (V <sub>D</sub> ⇒ Rated V <sub>DRM</sub> , gate open, T <sub>C</sub> = 105°C)	dv/dt	50	_	_	V/μs
Thermal Resistance (Junction to Case)	€JC		_	4	°C/W